

RoHS Compliant Product
A suffix of "-C" specifies halogen & lead-free

FEATURES

- Simplifies Circuit Design.
- We Declare that the material of product compliance with RoHS requirements.

MARKING

2A

3N

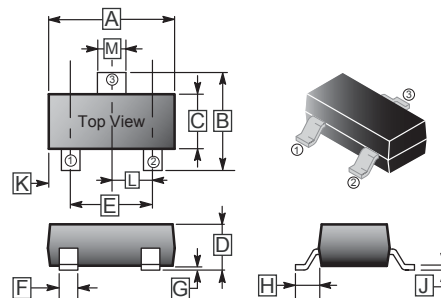
PACKAGE INFORMATION

Package	MPQ	Leader Size
SOT-523	3K	7 inch

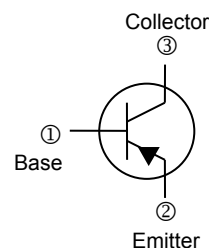
ORDER INFORMATION

Part Number	Type
MMBT3906FW	Lead (Pb)-free
MMBT3906FW-C	Lead (Pb)-free and Halogen-free

SOT-523



REF.	Millimeter		REF.	Millimeter	
	Min.	Max.		Min.	Max.
A	1.5	1.7	G	-	0.1
B	1.45	1.75	H	0.55 REF.	-
C	0.7	0.9	J	0.1	0.2
D	0.7	0.9	K	-	-
E	0.9	1.1	L	0.5 TYP.	-
F	0.15	0.25	M	0.25	0.35



MAXIMUM RATINGS (at $T_a = 25^\circ\text{C}$ unless otherwise specified)

Parameter	Symbol	Ratings	Unit
Collector - Emitter Voltage	V_{CEO}	-40	Vdc
Collector - Base Voltage	V_{CBO}	-40	Vdc
Emitter - Base Voltage	V_{EBO}	-5	Vdc
Collector Current - Continuous	I_C	-200	mA _{dc}
Total Device Dissipation FR-4 Board ⁽¹⁾ $T_A=25^\circ\text{C}$, Derate above 25°C	P_D	200	mW
		1.6	mW/ $^\circ\text{C}$
Thermal Resistance, Junction to Ambient	$R_{\theta JA}$	600	$^\circ\text{C} / \text{W}$
Total Device Dissipation FR-4 Board ⁽²⁾ $T_A=25^\circ\text{C}$, Derate above 25°C	P_D	300	mW
		2.4	mW/ $^\circ\text{C}$
Thermal Resistance, Junction to Ambient	$R_{\theta JA}$	400	$^\circ\text{C} / \text{W}$
Junction & Storage Temperature	T_J, T_{STG}	-55 ~ 150	$^\circ\text{C}$

Note:

1. FR-4 Minimum Pad.
2. FR-4 1.0 X 1.0 Inch Pad.
3. Pulse Test : Pulse Width $\leq 300 \mu\text{s}$, Duty Cycle $\leq 2.0\%$.

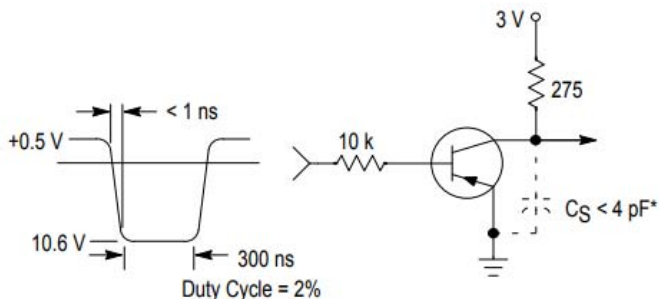
ELECTRICAL CHARACTERISTICS (at $T_a = 25^\circ\text{C}$ unless otherwise specified)

Parameter	Symbol	Min.	Max.	Unit	Test conditions
Off Characteristics					
Collector-Emitter Breakdown Voltage ¹	V _{(BR)CEO}	-40	-	V	I _C = -1.0 mA, I _B = 0
Collector-Base Breakdown Voltage	V _{(BR)CBO}	-40	-	V	I _C = -10 μA, I _E = 0
Emitter-Base Breakdown Voltage	V _{(BR)EBO}	-5.0	-	V	I _E = -10 μA, I _C = 0
Collector Cut-Off Current	I _{BL}	-	-50	nA	V _{CE} = -30 V, V _{EB} = -3V
Emitter Cut-Off Current	I _{CEX}	-	-50	nA	V _{CE} = -30 V, V _{EB} = -3V
On Characteristics ⁽¹⁾					
DC Current Gain ⁽¹⁾	h _{FE}	60	-		I _C = -0.1mA, V _{CE} = -1V
		80	-		I _C = -1mA, V _{CE} = -1V
		100	300		I _C = -10mA, V _{CE} = -1V
		60	-		I _C = -50mA, V _{CE} = -1V
		30	-		I _C = -100mA, V _{CE} = -1V
Collector-Emitter Saturation Voltage ¹	V _{CE(sat)}	-	-0.25	V	I _C = -10mA, I _B = -1mA
		-	-0.4		I _C = -50mA, I _B = -5mA
Base-Emitter Saturation Voltage ¹	V _{BE(sat)}	-0.65	-0.85	V	I _C = -10mA, I _B = -1mA
		-	-0.95		I _C = -50mA, I _B = -5mA
Small-Signal Characteristics					
Current-Gain-Bandwidth Product	f _T	250	-	MHz	V _{CE} = -20 V, I _C = -10 mA, f = 100 MHz
Output Capacitance	C _{obo}	-	4.5	pF	V _{CB} = -5.0V, I _E = 0, f = 1MHz
Input Capacitance	C _{ibo}	-	10	pF	V _{EB} = -0.5V, I _E = 0, f = 1MHz
Input Impedance	h _{ie}	2.0	12	pF	V _{CE} = -10V, I _C = -1mA, f = 1kHz
Voltage Feedback Ratio	h _{re}	0.1	10	X10 ⁻⁴	V _{CE} = -10V, I _C = -1mA, f = 1kHz
Small-Signal Current Gain	h _{fe}	100	400	-	V _{CE} = -10V, I _C = -1mA, f = 1kHz
Output Admittance	*h _{oe}	3.0	60	μmhos	V _{CE} = -10V, I _C = -1mA, f = 1kHz
Noise Figure	NF	-	4.0	dB	V _{CE} = -5V, I _C = -100μA, R _S = 1k Ω, f = 1kHz
Switching Characteristics					
Delay Time	T _d	-	35	nS	V _{CC} = -3V, V _{BE} = -0.5V, I _C = -10mA, I _{B1} = -1mA
Rise Time	T _r	-	35	nS	
Storage Time	T _s	-	225	nS	V _{CC} = -3V, I _C = -10mA, I _{B1} = I _{B2} = -1mA
Fall Time	T _F	-	75	nS	

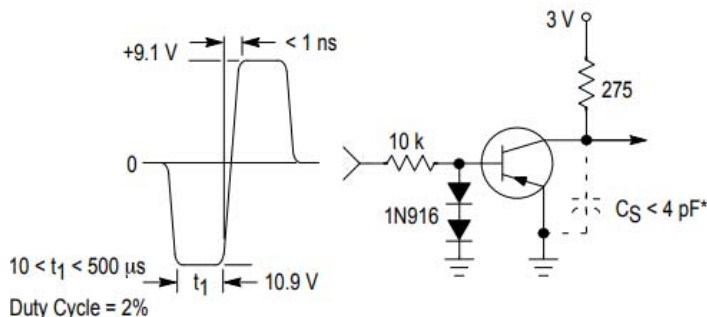
Note:

1. Pulse Test : Pulse Width $\leq 300\text{ }\mu\text{s}$, Duty Cycle $\leq 2.0\%$.

CHARACTERISTIC CURVES



**Figure 1. Delay and Rise Time
Equivalent Test Circuit**



**Figure 2. Storage and Fall Time
Equivalent Test Circuit**

* Total shunt capacitance of test jig and connectors

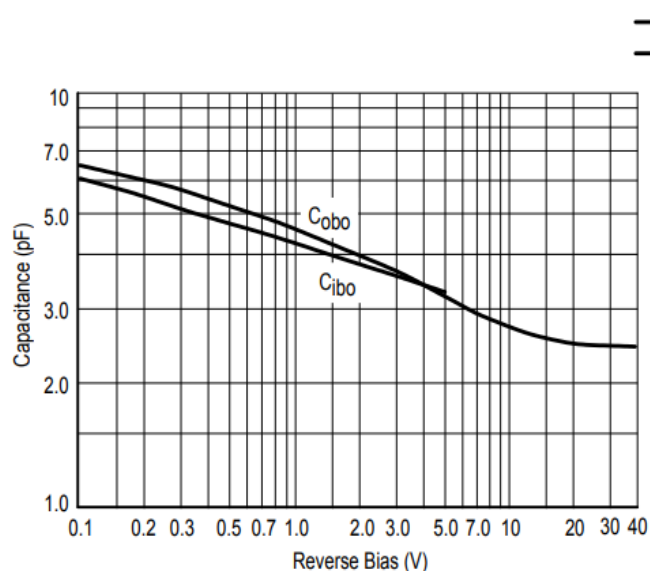


Figure 3. Capacitance

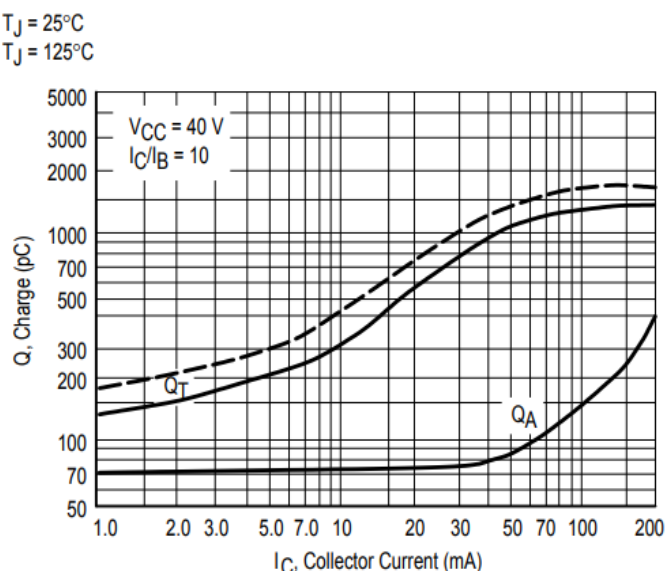


Figure 4. Charge Data

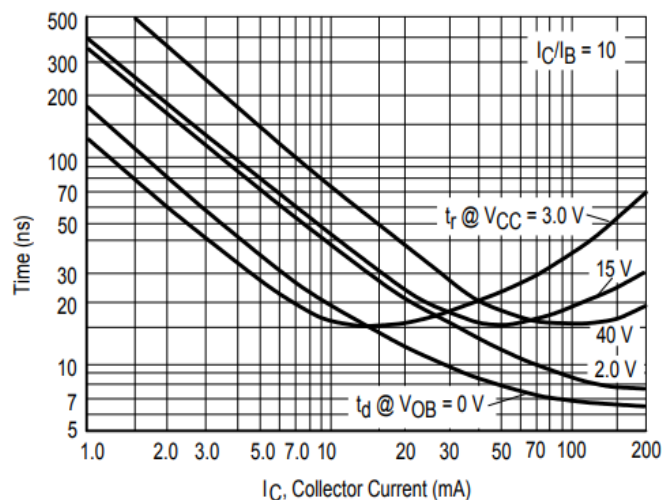


Figure 5. Turn-On Time

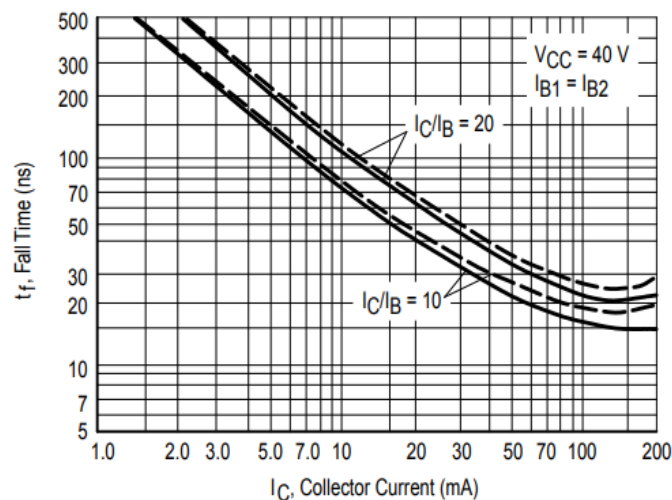


Figure 6. Fall Time

CHARACTERISTIC CURVES

TYPICAL AUDIO SMALL-SIGNAL CHARACTERISTICS NOISE FIGURE VARIATIONS

($V_{CE} = -5.0$ Vdc, $T_A = 25^\circ\text{C}$, Bandwidth = 1.0 Hz)

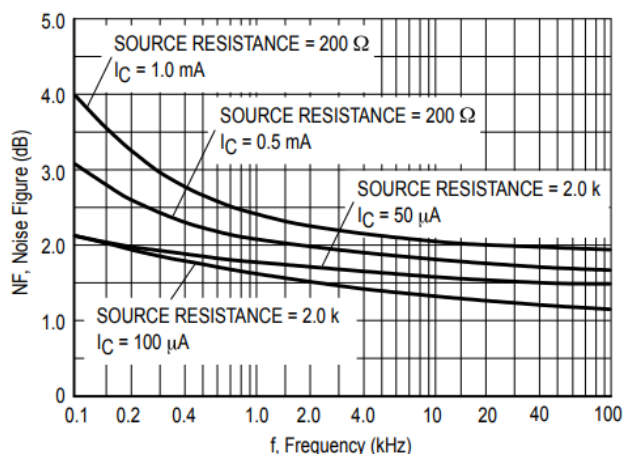


Figure 7.

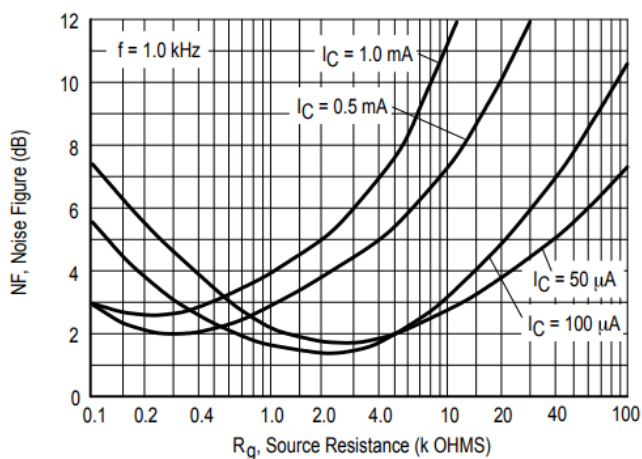


Figure 8.

h PARAMETERS

($V_{CE} = -10$ Vdc, $f = 1.0$ kHz, $T_A = 25^\circ\text{C}$)

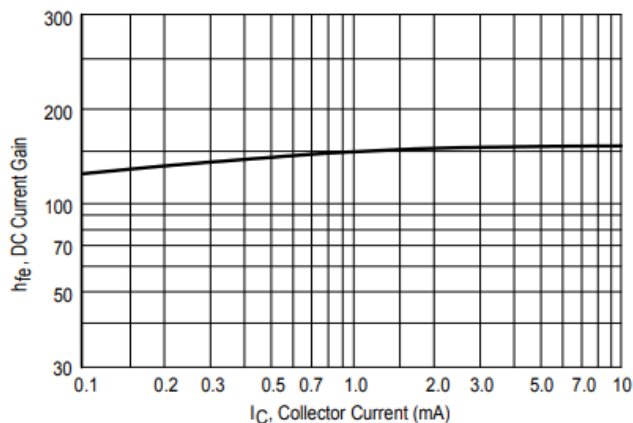


Figure 9. Current Gain

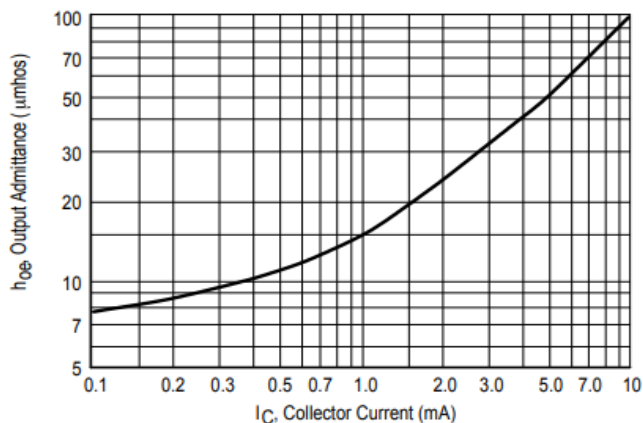


Figure 10. Output Admittance

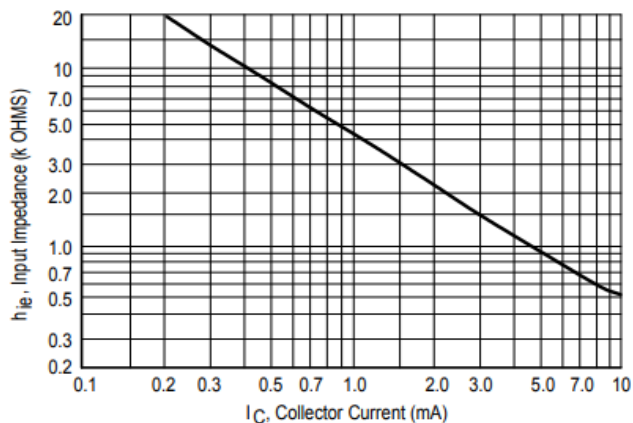


Figure 11. Input Impedance

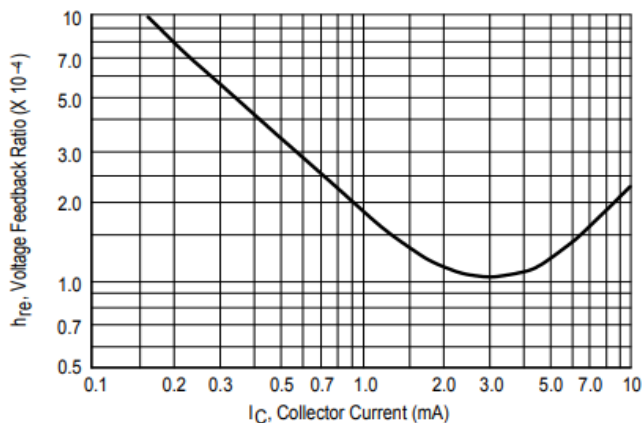


Figure 12. Voltage Feedback Ratio

CHARACTERISTIC CURVES

TYPICAL STATIC CHARACTERISTICS

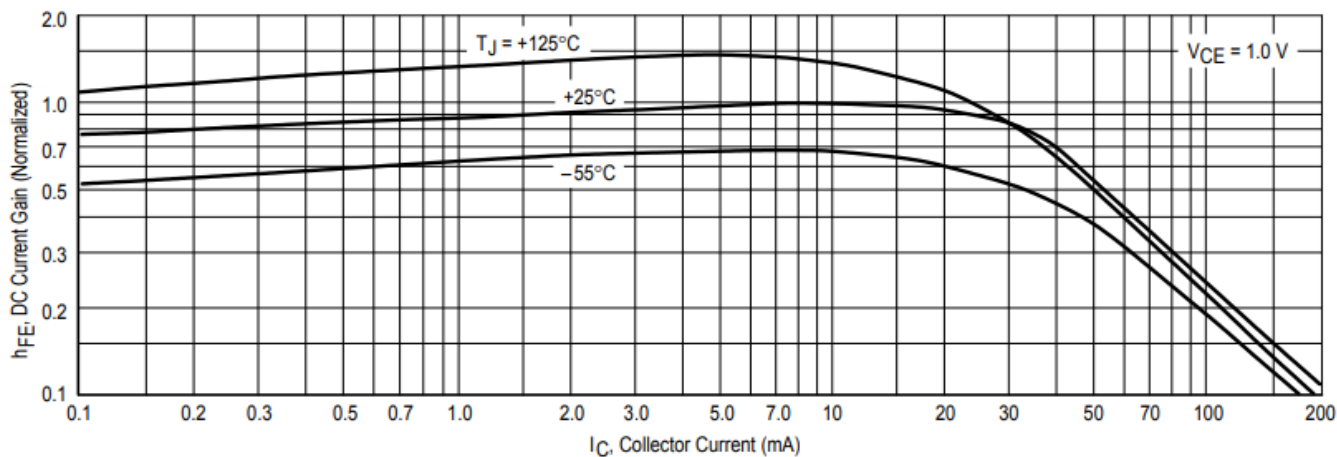


Figure 13. DC Current Gain

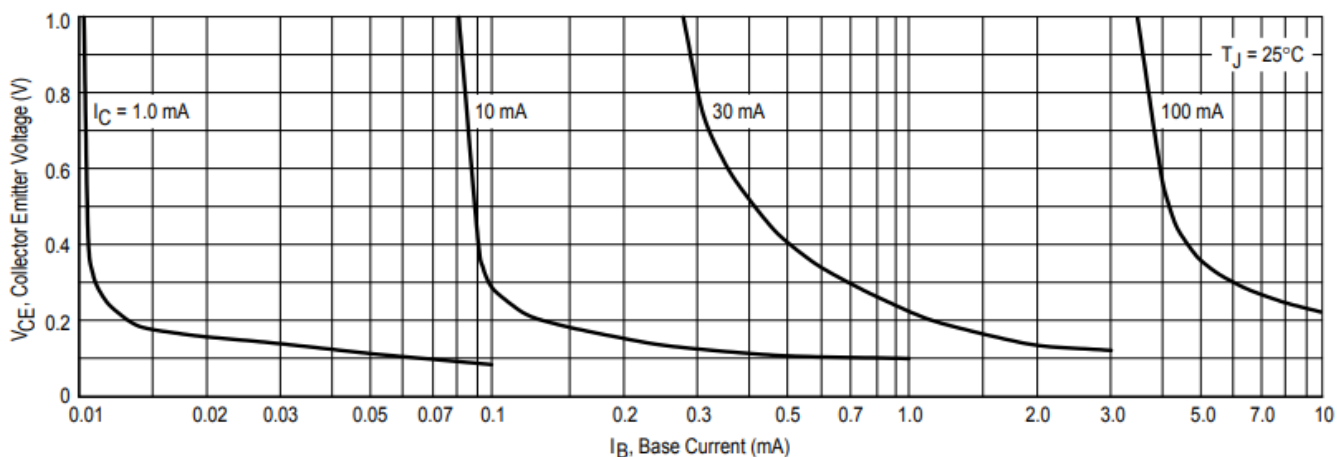


Figure 14. Collector Saturation Region

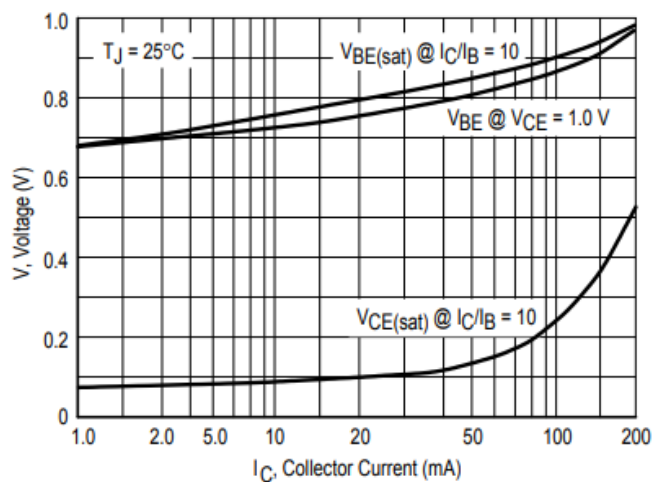


Figure 15. "ON" Voltages

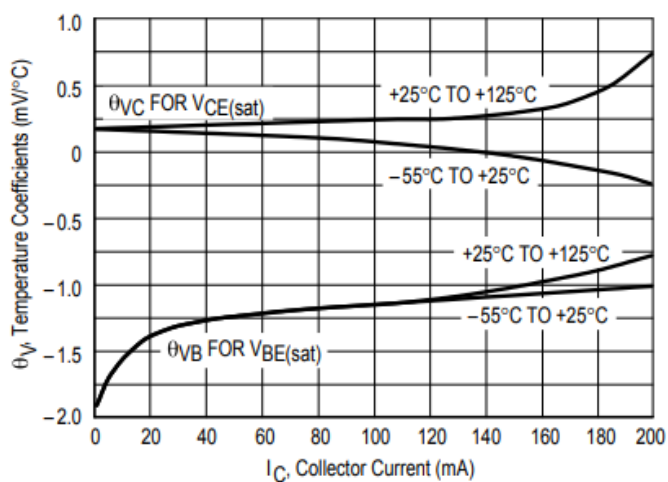


Figure 16. Temperature Coefficients